

**N-Ch MOSFET** 

#### **General Description**

Features

The WST6008 is the highest performance trench N-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the small power switching and load switch applications.

The WST6008 meet the RoHS and Green Product requirement with full function reliability approved.

• Low Gate Charge for Fast Switching

· We declare that the material of product is ROHS

• Small 1.6 X 1.6 mm Footprint

compliant and halogen free.

• ESD Protected Gate

#### **Product Summery**

BVDSS	RDSON	ID
30V	140mΩ	154mA

#### Applications

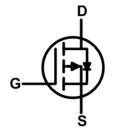
• Power Management Load Switch

Level Shift

Portable Applications such as Cell Phones, Media
Players, Digital Cameras, PDA's, Video Games,
Hand Held Computers, etc.

#### SOT-523 Pin Configuration





### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	±10	V
I <sub>D</sub> @T <sub>A</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	154	mA
I <sub>D</sub> @T <sub>A</sub> =70℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	120	mA
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	618	mA
P <sub>D</sub> @T <sub>A</sub> =25℃	Total Power Dissipation <sup>3</sup>	300	mW
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>	416		°C/W



**N-Ch MOSFET** 

## Electrical Characteristics (T<sub>J</sub>=25 $\odot$ , unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =100uA	30			V	
$\triangle BV_{DSS} / \triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to $25^{\circ}$ C , I <sub>D</sub> =1mA		0.05		V/℃	
Б	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =4.5V , I <sub>D</sub> =154mA		1.4	7.0	0	
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> =2.5V , I <sub>D</sub> =154mA		2.3	7.5		
V <sub>GS(th)</sub>	Gate Threshold Voltage		0.5	1.0	1.5	V	
$ riangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	──V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =100uA		0.9		mV/℃	
	Drain-Source Leakage Current	V <sub>DS</sub> =30V , V <sub>GS</sub> =0V , T <sub>J</sub> =25℃			1.0	uA	
I <sub>DSS</sub>		V <sub>DS</sub> =20V , V <sub>GS</sub> =0V , T <sub>J</sub> =85℃			1.0		
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm5V$ , $V_{DS}$ =0V			±1.0	uA	
gfs	Forward Transconductance V <sub>DS</sub> =5V , I <sub>D</sub> =0.1A			80		mS	
T <sub>d(on)</sub>	Turn-On Delay Time			13			
Tr	Rise Time	$V_{DS}$ =5V , $V_{GS}$ =4.5V ,		15			
T <sub>d(off)</sub>	Turn-Off Delay Time	R <sub>G</sub> =10Ω, I <sub>D</sub> =75mA		98		ns	
T <sub>f</sub>	Fall Time			60			
Ciss	Input Capacitance			11.5			
C <sub>oss</sub>	Dutput Capacitance $V_{DS}$ =5V , $V_{GS}$ =0V , f=1MHz			10		pF	
Crss	Reverse Transfer Capacitance			3.5			

#### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current <sup>1,4</sup>				100	mA
I <sub>SM</sub>	Pulsed Source Current <sup>2,4</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			0.4	А
V <sub>SD</sub>	Diode Forward Voltage <sup>2</sup>	$V_{GS}$ =0V , $I_{S}$ =0.154mA , $T_{J}$ =25 $^{\circ}$ C		0.77	0.9	V

Note :

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.

2.The data tested by pulsed , pulse width  $\,\leq\,$  300us , duty cycle  $\,\leq\,$  2%

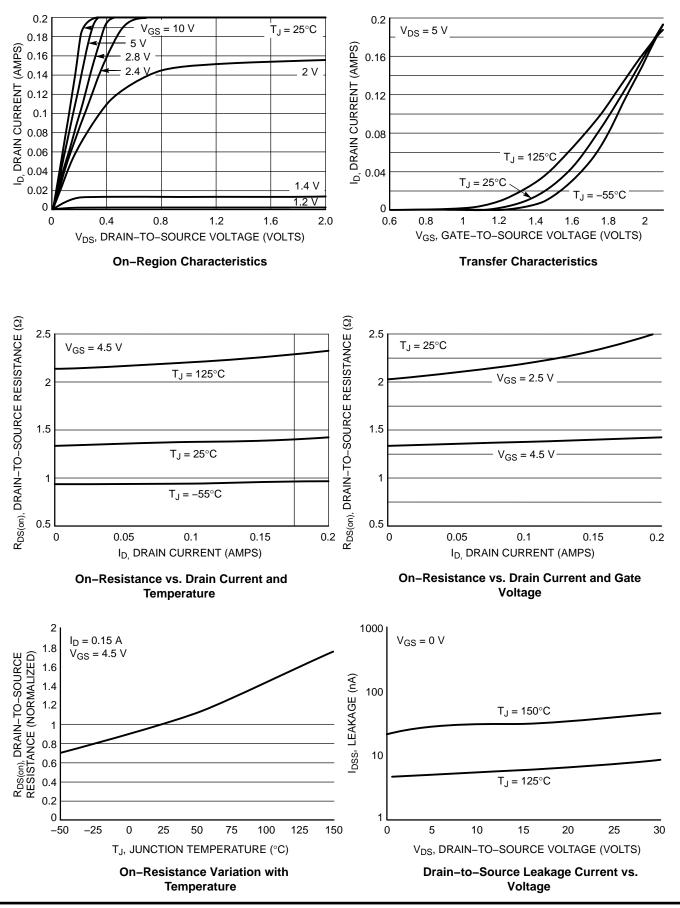
3. The power dissipation is limited by  $150^{\circ}$  junction temperature.

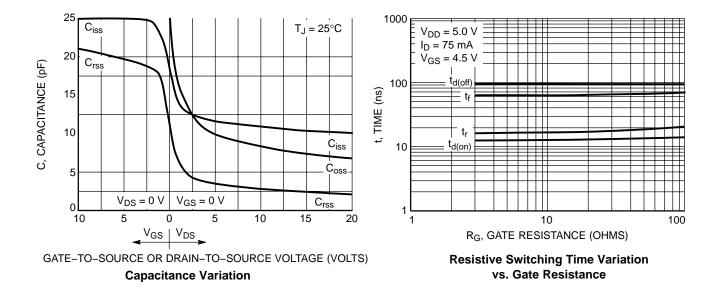
4. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.

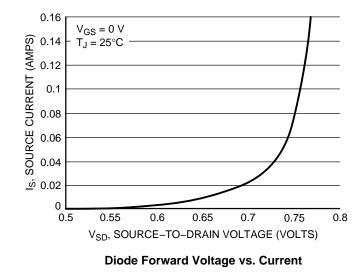


**N-Ch MOSFET** 

#### **Typical Performance Characteristics**



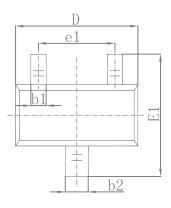


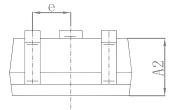


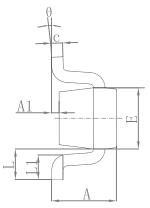


**N-Ch MOSFET** 

# SOT-523 Package Outline Dimensions

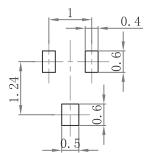






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

## SOT-523 Suggested Pad Layout





## Attention

1, Any and all Winsok power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your Winsok power representative nearest you before using any Winsok power products described or contained herein in such applications.

2, Winsok power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all Winsok power products described or contained herein.

3, Specifications of any and all Winsok power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

4, Winsok power Semiconductor CO., LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

5, In the event that any or all Winsok power products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

6, No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of Winsok power Semiconductor CO., LTD.

7, Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. Winsok power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

8, Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the Winsok power product that you Intend to use.

9, this catalog provides information as of Sep.2014. Specifications and information herein are subject to change without notice.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Winsok manufacturer:

Other Similar products are found below :

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ NTNS3A92PZT5G IRFD120 IRFF430 JANTX2N5237 2N7000 AOD464 2SK2267(Q) 2SK2545(Q,T) 405094E 423220D MIC4420CM-TR VN1206L 614234A 715780A 751625C IPS70R2K0CEAKMA1 BSF024N03LT3 G PSMN4R2-30MLD TK31J60W5,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 EFC2J004NUZTDG FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE2384 NTE2969 NTE6400A DMC2700UDMQ-7 DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 SSM6P54TU,LF DMP22D4UFO-7B IPS60R3K4CEAKMA1 DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6 C3M0021120D DMN6022SSD-13